## General Description

The MAX606/MAX607 are the smallest CMOS, step-up DC-DC converters available for flash memory and PC (PCMCIA) cards. They switch at up to 1 MHz , permitting the entire circuit to fit in $0.25 \mathrm{in}^{2}$, yet remain under 1.35 mm high to fit Type 1, 2, and 3 card standards. These devices operate from a 3 V to 5.5 V input and provide a $\pm 4 \%$-accurate output that is preset to 5 V or 12 V , or adjustable from $\mathrm{V}_{\mathrm{IN}}$ to 12.5 V . Their guaranteed output current is 60 mA at 12 V .
The MAX606 switches at up to 1 MHz and fits Type 1 (thinnest standard) flash memory and PCMCIA cards. It uses a thin, 1.19 mm high, $5 \mu \mathrm{H}$ inductor and small, $0.68 \mu \mathrm{~F}$ output capacitors. The entire circuit fits in $0.25 \mathrm{in}^{2}$ and is less than 1.35 mm high.
The MAX607 switches at up to 500 kHz , fitting Type 2 and 3 cards, as well as hand-held devices where height requirements are not as critical. It uses less board area than the MAX606, fitting in $0.16 \mathrm{in}^{2}$, but requires 2.5 mm of height. It also has a lower no-load supply current than the MAX606.
Both devices use a unique, current-limited pulse-fre-quency-modulation (PFM) control scheme that optimizes efficiency over all input and output voltages. Other features include $1 \mu \mathrm{~A}$ logic-controlled shutdown and usercontrolled soft-start to minimize inrush currents.
The MAX606/MAX607 come in 8-pin $\mu \mathrm{MAX}$ and SO packages. The $\mu$ MAX package uses half the board area of a standard 8-pin SO and has a maximum height of just 1.11 mm .

Applications
PCMCIA Cards
Memory Cards
Single PCMCIA Slot Programming
Digital Cameras
Flash Memory Programming
Hand-Held Equipment
Pin Configuration


Features

- Lowest-Height Circuit (1.35mm, max)
- $\pm 4 \%$ Regulated Output (5V, 12V, or Adjustable)
- Guaranteed 60mA Output at 12V
- 1MHz Switching Frequency (MAX606)
- $1 \mu \mathrm{~A}$ Logic-Controlled Shutdown
- 3V to 5.5V Input Voltage Range
- Compact 8-Pin $\mu$ MAX Package

| PART | TEMP. RANGE | PIN-PACKAGE |
| :--- | ---: | :--- |
| MAX606C/D | $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ | Dice ${ }^{*}$ |
| MAX606ESA | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 8 SO |
| MAX606EUA | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | $8 \mu \mathrm{MAX}$ |
| MAX607C/D | $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ | Dice ${ }^{\star}$ |
| MAX607ESA | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 8 SO |
| MAX607EUA | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | $8 \mu \mathrm{MAX}$ |

* Contact factory for dice specifications.


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## Low-Profile, 5V/12V or Adjustable, Step-Up DC-DC Converters for Flash Memory/PCMCIA Cards

## ABSOLUTE MAXIMUM RATINGS

| IN to GND | -0.3 V to +6 V |
| :---: | :---: |
| LX, OUT to GND | .........-0.3V to +15V |
| PGND to GND. | ............. $\pm 0.3 \mathrm{~V}$ |
| FB to GND . | . 0.3 V to ( $\mathrm{V}_{C C}+0.3 \mathrm{~V}$ ) |
| SS, SHDN to GND | -0.3V to +6V |


| inuous Power Dissipation ( $\mathrm{T}_{\mathrm{A}}=+70^{\circ} \mathrm{C}$ ) |  |
| :---: | :---: |
| SO (derate $5.88 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $+70^{\circ} \mathrm{C}$ ) ..................... 471 mW |  |
| $\mu \mathrm{MAX}$ (derate $4.10 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $+70^{\circ} \mathrm{C}$ ) | . 330 mW |
| Operating Temperature Range ........................ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |  |
| Storage Temperature ................................................. $160^{\circ} \mathrm{C}$ |  |
| Lead Temperature (soldering, 10sec) .......................... $300^{\circ} \mathrm{C}$ |  |

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS

$\left(\mathrm{V} I \mathrm{~N}=3.3 \mathrm{~V}, \mathrm{GND}=\mathrm{PGND}=\mathrm{FB}=0 \mathrm{~V}, \overline{S H D N}=\mathbb{N}, \mathrm{T}_{\mathrm{A}}=0^{\circ} \mathrm{C}\right.$ to $+85^{\circ} \mathrm{C}$, unless otherwise noted. Typical values are at $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$.)

| PARAMETER | CONDITIONS |  | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage |  |  | 3.0 |  | 5.5 | V |
| Undervoltage Lockout Threshold |  |  |  | 2.4 | 2.8 | V |
| Output Voltage | $\begin{aligned} & 3 \mathrm{~V}<\mathrm{V}_{\mathrm{IN}}<5.5 \mathrm{~V} \\ & \text { (Note 1) } \end{aligned}$ | FB $=1 \mathrm{~N}, \mathrm{~L}$ LOAD $=0 \mathrm{~mA}$ to 90 mA | 4.8 | 5.0 | 5.2 | V |
|  |  | FB $=$ GND, ILOAD $=0 \mathrm{~mA}$ to 60 mA | 11.5 | 12.0 | 12.5 |  |
| FB Regulation Setpoint | $0.1 \mathrm{~V}<\mathrm{V}_{\text {FB }}<\left(\mathrm{V}_{\text {IN }}-0.1 \mathrm{~V}\right)$ |  | 1.96 | 2.00 | 2.04 | V |
| Adjustable Output Voltage Range | $0.1 \mathrm{~V}<\mathrm{V}_{\mathrm{FB}}<\left(\mathrm{V}_{\text {IN }}-0.1 \mathrm{~V}\right)$ |  | V IN |  | 12.5 | V |
| Line Regulation | $\mathrm{V}_{\mathrm{IN}}=3 \mathrm{~V}$ to 5.5 V |  |  | 0.5 |  | \% |
| Switch On-Resistance |  |  |  | 0.4 | 1 | $\Omega$ |
| Switch Off Leakage | $V_{L X}=12 \mathrm{~V}$ |  |  |  | 10 | $\mu \mathrm{A}$ |
| Switch Current Limit | $\mathrm{V} \overline{\text { SHDN }}=\mathrm{V}_{\text {IN }}, \mathrm{V}_{\text {SS }}=150 \mathrm{mV}$ |  | 0.7 |  | 1.1 | A |
| SS Resistance |  |  | 30 | 45 | 60 | , |
|  | $\mathrm{V} \overline{\mathrm{SHDN}}=\mathrm{V}_{\text {SS }}=0 \mathrm{~V}$ |  |  |  | 0.5 | k |
| Quiescent Supply Current | VOUT $=13 \mathrm{~V}$ | MAX606 |  | 250 | 500 |  |
|  |  | MAX607 |  | 150 | 300 | $\mu \mathrm{A}$ |
| Shutdown Quiescent Current | $\mathrm{V} \overline{\mathrm{SHDN}}=0 \mathrm{~V}, \mathrm{OUT}=\mathrm{IN}$ |  |  | 0.01 | 10 | $\mu \mathrm{A}$ |
| OUT Input Current | VOUT $=13 \mathrm{~V}$ |  |  |  | 80 | $\mu \mathrm{A}$ |
| Switch On-Time Constant (K) | $\begin{aligned} & 3 \mathrm{~V}<\mathrm{V} \text { IN }<5.5 \mathrm{~V} \\ & (\mathrm{ton}=\mathrm{K} / \mathrm{VIN}) \end{aligned}$ | MAX606 | 1.9 | 3.0 | 4.3 | s-V |
|  |  | MAX607 | 3.8 | 6.0 | 8.6 | $\mu \mathrm{S}-\mathrm{V}$ |
| Switch Off-Time Ratio | $2 \mathrm{~V}<\left(\mathrm{V}_{\text {OUT }}+0.5 \mathrm{~V}-\mathrm{V}\right.$ IN $)<8 \mathrm{~V}$ (see Pulse-Frequency-Modulation Control Scheme section) |  | 0.3 |  | 0.7 |  |
| SHDN Input Low Voltage | $\mathrm{V}_{\mathrm{IN}}=3 \mathrm{~V}$ |  |  |  | $0.25 \mathrm{~V}_{\text {IN }}$ | V |
| SHDN Input High Voltage | $\mathrm{V}_{\mathrm{IN}}=5.5 \mathrm{~V}$ |  | $0.66 \mathrm{~V}_{\text {IN }}$ |  |  | V |
| $\overline{\text { SHDN }}$ Input Current | $\mathrm{V} \overline{\text { SHDN }}=0 \mathrm{~V}$ or VIN |  |  |  | $\pm 1$ | $\mu \mathrm{A}$ |
| FB Input Low Voltage | $\mathrm{V}_{\mathrm{IN}}=3 \mathrm{~V}$ to 5.5 V . For $\mathrm{V}_{\mathrm{FB}}$ below this voltage, output regulates to 12 V . |  |  |  | 0.1 | V |
| FB Input High Voltage | $\mathrm{V}_{\mathrm{IN}}=3 \mathrm{~V}$ to 5.5 V . For $\mathrm{V}_{\mathrm{FB}}$ above this voltage, output regulates to 5 V . |  | VIN - 0.1 |  |  | V |
| FB Input Current | $\mathrm{V}_{\mathrm{FB}}=2.05 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=13 \mathrm{~V}$ |  |  |  | 200 | nA |

## Low-Profile, 5V/12V or Adjustable, Step-Up DC-DC Converters for Flash Memory/PCMCIA Cards

## ELECTRICAL CHARACTERISTICS (continued)

$\left(\mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}, \mathrm{GND}=\mathrm{PGND}=\mathrm{FB}=\mathrm{OV}, \mathrm{SHDN}=\mathbb{I N}, \mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}\right.$ to $+85^{\circ} \mathrm{C}$, unless otherwise noted.) (Note 2)

| PARAMETER | CONDITIONS |  | MIN | TYP MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage |  |  | 3.0 | 5.5 | V |
| Undervoltage Lockout Threshold |  |  |  | 2.8 | V |
| Output Voltage | $\begin{aligned} & 3 \mathrm{~V}<\mathrm{V} \mathbb{I N}<5.5 \mathrm{~V} \\ & \text { (Note 1) } \end{aligned}$ | $\mathrm{FB}=\mathrm{IN}, \mathrm{L}$ LOAD $=0 \mathrm{~mA}$ to 90 mA | 4.75 | 5.25 | V |
|  |  | FB $=$ GND, L LOAD $=0 \mathrm{~mA}$ to 60 mA | 11.4 | 12.6 |  |
| FB Regulation Setpoint | $0.1 \mathrm{~V}<\mathrm{V}_{\mathrm{FB}}<\left(\mathrm{V}_{\text {IN }}-0.1 \mathrm{~V}\right)$ |  | 1.94 | 2.06 | V |
| Adjustable Output Voltage Range | $0.1 \mathrm{~V}<\mathrm{V}_{\mathrm{FB}}<\left(\mathrm{V}_{\text {IN }}-0.1 \mathrm{~V}\right)$ |  | V IN | 12.5 | V |
| Switch On-Resistance |  |  |  | 1 | $\Omega$ |
| Switch Off Leakage | $V_{\mathrm{LX}}=12 \mathrm{~V}$ |  |  | 10 | $\mu \mathrm{A}$ |
| Switch Current Limit | $\mathrm{V} \overline{\text { SHDN }}=\mathrm{VIN}, \mathrm{V}$ SS $=150 \mathrm{mV}$ |  | 0.55 | 1.25 | A |
| SS Resistance |  |  | 30 | 60 |  |
|  | $\mathrm{V} \overline{\mathrm{SHDN}}=\mathrm{V}_{\text {SS }}=0 \mathrm{~V}$ |  |  | 0.5 | k $\Omega$ |
| Quiescent Supply Current | $\mathrm{V}_{\text {OUT }}=13 \mathrm{~V}$ | MAX606 |  | 500 | $\mu \mathrm{A}$ |
|  |  | MAX607 |  | 300 |  |
| Shutdown Quiescent Current | $\mathrm{V} \overline{\mathrm{SHDN}}=0 \mathrm{~V}, \mathrm{OUT}=\mathrm{IN}$ |  |  | 10 | $\mu \mathrm{A}$ |
| OUT Input Current | VOUT $=13 \mathrm{~V}$ |  |  | 85 | $\mu \mathrm{A}$ |
| Switch On-Time Constant (K) | $\begin{aligned} & 3 \mathrm{~V}<\mathrm{V}_{\mathrm{IN}}<5.5 \mathrm{~V} \\ & \text { (ton } \left.=\mathrm{K} / \mathrm{V}_{\mathrm{IN}}\right) \end{aligned}$ | MAX606 | 1.8 | 4.5 | $\mu \mathrm{s}-\mathrm{V}$ |
|  |  | MAX607 | 3.5 | 9.0 |  |
| Switch Off-Time Ratio | $2 \mathrm{~V}<(\mathrm{VOUT}+0.5 \mathrm{~V}-\mathrm{VIN})<8 \mathrm{~V}$ (see Pulse-Frequency-Modulation Control Scheme section) |  | 0.3 | 0.7 |  |
| SHDN Input Low Voltage | $\mathrm{V}_{\mathrm{IN}}=3 \mathrm{~V}$ |  |  | $0.25 \mathrm{~V}_{\text {IN }}$ | V |
| $\overline{\text { SHDN }}$ Input High Voltage | $\mathrm{V}_{\text {IN }}=5.5 \mathrm{~V}$ |  | 0.66 V IN |  | V |
| SHDN Input Current | V $\overline{\text { SHDN }}=0 \mathrm{~V}$ or $\mathrm{V}_{\text {IN }}$ |  |  | $\pm 1$ | $\mu \mathrm{A}$ |
| FB Input Low Voltage | $\mathrm{V}_{\mathrm{IN}}=3 \mathrm{~V}$ to 5.5 V . For $\mathrm{V}_{\mathrm{FB}}$ below this voltage, output regulates to 12 V . |  |  | 0.1 | V |
| FB Input High Voltage | $\mathrm{V}_{\mathrm{IN}}=3 \mathrm{~V}$ to 5.5 V . For $\mathrm{V}_{\mathrm{FB}}$ above this voltage, output regulates to 5 V . |  | VIN - 0.1 |  | V |
| FB Input Current | $\mathrm{V}_{\mathrm{FB}}=2.05 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=13 \mathrm{~V}$ |  |  | 200 | nA |

Note 1: The load specification is guaranteed by DC parametric tests and is not production tested in circuit.
Note 2: Specifications to $-40^{\circ} \mathrm{C}$ are guaranteed by design, not production tested.

## Low-Profile, 5V/12V or Adjustable, Step-Up DC-DC Converters for Flash Memory/PCMCIA Cards

## MAX606/MAX607









## Low-Profile, 5V/12V or Adjustable, Step-Up DC-DC Converters for Flash Memory/PCMCIA Cards



## Low-Profile, 5V/12V or Adjustable, Step-Up

 DC-DC Converters for Flash Memory/PCMCIA Cards
$\mathrm{L}_{\text {LOAD }}=5 \mathrm{~mA}$ to 60 mA, OUTPUT $=12 \mathrm{~V}, \mathrm{INPUT}=3.3 \mathrm{~V}$

MAX606 LINE-TRANSIENT RESPONSE

$\mathrm{L}_{\text {LOAD }}=10 \mathrm{~mA}$, OUTPUT $=12 \mathrm{~V}$, INPUT $=3.3 \mathrm{~V}$ TO 4.3 V

$\mathrm{L}_{\text {LOAD }}=5 \mathrm{~mA}$ to 60 mA , OUTPUT $=12 \mathrm{~V}, \mathrm{INPUT}=3.3 \mathrm{~V}$

MAX607 LINE-TRANSIENT RESPONSE

$I_{\text {LOAD }}=10 \mathrm{~mA}$, OUTPUT $=12 \mathrm{~V}, \operatorname{INPUT}=3.3 \mathrm{~V}$ TO4.3V

# Low-Profile, 5V/12V or Adjustable, Step-Up DC-DC Converters for Flash Memory/PCMCIA Cards 

| PIN | NAME | FUNCTION |
| :---: | :---: | :--- |
| 1 | PGND | Power Ground. Source of N-channel power MOSFET. |
| 2 | FB | Feedback Input. Connect to IN for 5V output, to GND for 12 V output, or to a resistive voltage divider between <br> OUT and GND for an adjustable output between IN and 12.5V. |
| 3 | $\overline{S H D N}$ | Shutdown Input, active low. Connect to GND to power down, or to IN for normal operation. Output power FET <br> is held off when SHDN is low. |
| 4 | IN | Supply Voltage Input: 3.0 V to 5.5 V |
| 5 | GND | Analog Ground |
| 7 | SS | Soft-Start Input |
| 8 | OUT | Output. Always connect directly to the circuit output. |



Figure 1. 12V Standard Application Circuit


Figure 2. 5V Standard Application Circuit
produces 5 V at a typical output current of 120 mA from a 3.3V input. Each application circuit is designed to deliver the full rated output load current over the temperature range listed. Component values and part numbers for this circuit are listed in Table 2. See Table 3 for component suppliers' phone and fax numbers.

# Low-Profile, 5V/12V or Adjustable, Step-Up DC-DC Converters for Flash Memory/PCMCIA Cards 

Table 1. Suggested Components for 12V Standard Application Circuit of Figure 2

| DESIGNATION | MAX606 | MAX607 |
| :---: | :--- | :--- |
| L1 | $5 \mu \mathrm{H}$ inductor <br> Dale ILS-3825-XX | $10 \mu \mathrm{H}$ inductor <br> Sumida CLS62-100 |
| D1 | 0.5A, 20V diode <br> Motorola MBR0520L | $0.5 \mathrm{~A}, 20 \mathrm{~V}$ diode <br> Motorola MBR0520L |
| C1 | $0.1 \mu \mathrm{~F}$ ceramic cap. | $0.1 \mu \mathrm{~F}$ ceramic cap. |
| C2 | $2 \times 0.68 \mu \mathrm{~F}$ ceramic cap. <br> Marcon <br> THCR20E1E684Z | $2.2 \mu \mathrm{~F}$ ceramic cap. <br> Marcon <br> THCR30E1E225M |
| C3 | $2 \times 0.68 \mu F$ ceramic cap. <br> Marcon <br> THCR20E1E684Z | $2 \times 1 \mu \mathrm{~F} \mathrm{ceramic} \mathrm{cap}$. <br> Marcon <br> THCR30E1E105M |
| C4 | 10nF ceramic cap. | 10nF ceramic cap. |

## Detailed Description

The remainder of this document contains the detailed information you'll need to design a circuit that differs from the two Standard Application Circuits. If you are using one of the predesigned circuits, the following sections are purely informational.
The MAX606/MAX607 CMOS, step-up DC-DC converters employ a current-limited pulse-frequency modulation (PFM) control scheme. This PFM control scheme regulates a boost topology to convert input voltages between 3 V and 5.5 V into either a pin-programmable $5 \mathrm{~V} / 12 \mathrm{~V}$ output, or an adjustable output between VIN and 12.5 V . It optimizes performance over all input and output voltages, and guarantees output accuracy to $\pm 4 \%$.
The ultra-high switching frequency (typically 1 MHz for the MAX606 and 0.5 MHz for the MAX607) permits the use of extremely small external components, making these converters ideal for use in Types 1, 2, and 3 flash memory and PCMCIA applications.

## Pulse-Frequency-Modulation Control Scheme

The MAX606/MAX607 employ a proprietary, currentlimited PFM control scheme that combines the ultra-low supply current of traditional pulse-skipping PFM converters with the high full-load efficiency of current-mode pulse-width-modulation (PWM) converters. This particular control scheme is similar to the one used in previous current-limited PFM devices, which governed the

Table 2. Suggested Components for 5 V Standard Application Circuit of Figure 1

| DESIGNATION | MAX606 | MAX607 |
| :---: | :--- | :--- |
| L1 | $5 \mu \mathrm{H}, 1 \mathrm{~A}$ inductor <br> Dale ILS-3825-XX | $10 \mu \mathrm{H}, 0.7 \mathrm{~A}$ inductor <br> Sumida CLS62B-100 |
| D1 | $0.5 \mathrm{~A}, 20 \mathrm{~V}$ diode <br> Motorola MBR0520L | 0.5 A, 20V diode <br> Motorola MBR0520L |
| C1 | $0.1 \mu$ F ceramic cap. | $0.1 \mu \mathrm{~F}$ ceramic cap. |
| C2 | $2 \times 0.68 \mu$ F ceramic cap. <br> Marcon <br> THCR20E1E684Z | $2.2 \mu \mathrm{~F}$ ceramic cap. <br> Marcon <br> THCR30E1E225M |
| C3 | $4.7 \mu \mathrm{~F}$ ceramic cap. <br> Marcon <br> THCR30E1E475M | 4.7 $\mu \mathrm{F}$ ceramic cap. <br> Marcon <br> THCR30E1E475M |
| C4 | 10nF ceramic cap. | 10nF ceramic cap. |

Table 3. Component Suppliers

| SUPPLIER | PHONE | FAX |
| :--- | :---: | :---: |
| Dale Inductors | $(605) 668-4131$ | $(605) 665-1627$ |
| Motorola | $(602) 244-3576$ | $(602) 244-4015$ |
| Sumida USA | $(708) 956-0666$ | $(708) 956-0702$ |
| Sumida Japan | $(03) 607-5111$ | $(03) 607-5144$ |
| Marcon/United <br> Chemi-Con | $(708) 696-2000$ | $(708) 518-9985$ |

switching current via maximum on-time, minimum offtime, and current limit, except it varies the on and off times according to the input and output voltages. This important feature enables the MAX606/MAX607 to achieve ultra-high switching frequencies while maintaining high output accuracy, low output ripple, and high efficiency over a wide range of loads and input/output voltages.
Figure 3 shows the functional diagram of the MAX606/ MAX607. The internal power MOSFET is turned on when the error comparator senses that the output is out of regulation. The power switch stays on until either the timing circuit turns it off at the end of the on-time, or the switch current reaches the current limit. Once off, the switch remains off during the off-time. Subsequently, if the output is still out of regulation, another switching cycle is initiated. Otherwise, the switch remains turned off as long as the output is in regulation.

## Low-Profile, 5V/12V or Adjustable, Step-Up DC-DC Converters for Flash Memory/PCMCIA Cards



Figure 3. Functional Diagram

The on/off times are determined by the input and output voltages:

$$
\begin{aligned}
& \text { toN }=\mathrm{K} / \mathrm{V} \text { IN } \\
& \text { tOFF }=0.5 \times \mathrm{K} /(\text { VOUT }+ \text { VDIODE }-\mathrm{VIN})
\end{aligned}
$$

K is typically $3 \mu \mathrm{~s}-\mathrm{V}$ for the MAX606 and $6 \mu \mathrm{~s}-\mathrm{V}$ for the MAX607. This factor is chosen to set the optimum switching frequency and the one-cycle current limit, which determines the no-load output ripple at low out-put-to-input voltage differentials. The factor of 0.5 in the off-time equation is the typical switch off-time ratio. This ratio guarantees high efficiency under a heavy load by allowing the inductor to operate in continuous-conduction mode. For example, a switch off-time ratio of 1 would cause the device to operate on the edge of dis-continuous-conduction mode.
To determine the actual switch off-time ratio for a particular device, measure ton, toff, ViN, and Vout, and
then solve for the ratio by substituting these values into the off-time equation.
Unlike PWM converters, the MAX606/MAX607 generate variable-frequency switching noise. However, the amplitude of this noise does not exceed the product of the switch current limit and the output capacitor equivalent series resistance (ESR). Traditional clocked-PFM or pulse-skipping converters cannot make this claim.

## Output Voltage Selection

The MAX606/MAX607 output voltage is pin-programmable to 5 V and 12 V , and also adjustable to voltages between $\mathrm{V}_{\mathrm{IN}}$ and 12.5 V . Connect FB to IN for a 5 V output, to GND for a 12 V output, or to a resistive divider between the output and GND for an adjustable output. Always connect OUT to the output.
When FB is connected to IN or GND, an internal voltage divider is configured to produce a predetermined

## Low-Profile, 5V/12V or Adjustable, Step-Up DC-DC Converters for Flash Memory/PCMCIA Cards



Figure 4. Adjustable Output Voltage
output. However, when the voltage at FB is between 0.1 V above ground and 0.1 V below V IN , the device is in the adjustable output mode. In this mode, the MAX606/MAX607 output voltage is set by two external resistors, R1 and R2 (Figure 4), which form a voltage divider between the output and FB. Use the following equation to determine the output voltage:
VOUT = VREF (R1 / R2 + 1)
where $\mathrm{V}_{\mathrm{REF}}=2 \mathrm{~V}$. To simplify the resistor selection:

$$
\mathrm{R} 1=\mathrm{R} 2[(\mathrm{VOUT} / \mathrm{V} \text { REF })-1]
$$

Since the input current at FB is 200 nA maximum, large values (up to $100 \mathrm{k} \Omega$ ) can be used for R2 with no significant loss of accuracy. For $1 \%$ error, the current through R2 should be at least 100 times the FB input bias current.

Soft-Start
Connecting a capacitor to the Soft-Start (SS) pin ensures a gradually increasing current limit during power-up or when exiting shutdown, thereby reducing initial inrush currents. This feature can be useful, for example, when an old battery's increased series resistance limits initial inrush currents. Using the soft-start feature in a situation like this minimizes the risk of overloading the incoming supply.
Soft-start timing is controlled by the value of the SS capacitor. On power-up, the SS capacitor is charged by the 2 V reference through an internal, $45 \mathrm{k} \Omega$ pull-up resistor. As the voltage on the SS pin increases, the voltage at the SS clamp output also increases, which in turn raises the current-limit threshold. The Start-Up Delay vs. SS Capacitor graph in the Typical Operating Characteristics shows typical timing characteristics for
selected capacitor values and circuit conditions. The soft-start capacitor is discharged each time the MAX606 or MAX607 is put into shutdown, including during undervoltage lockout and when powering down at IN.
If the circuit is required to start up with no load, as in flash memory programming supplies, soft-start is not required. Omitting the soft-start capacitor permits a minimum output voltage rise time from the shutdown state, improving flash memory access time.

## Undervoltage Lockout

The MAX606/MAX607 monitor the supply voltage at IN and operate for supply voltages greater than 2.8 V . When an undervoltage condition is detected, control logic turns off the output power FET and discharges the soft-start capacitor to ground. The control logic holds the output power FET in an off state until the supply voltage rises above the undervoltage threshold, at which time a soft-start cycle begins.

Shutdown Mode
Connecting SHDN to GND will hold the MAX606/ MAX607 in shutdown mode. In shutdown, the output power FET is off, but there is still an external path from IN to the load via the inductor and diode. The internal reference also turns off, which causes the soft-start capacitor to discharge. Typical device standby current in shutdown mode is $0.01 \mu \mathrm{~A}$. For normal operation, connect SHDN to IN. A soft-start cycle is initiated when the MAX606/MAX607 exit shutdown.

## Applic ations Information

## Inductor Selection

Use a $5 \mu \mathrm{H}$ inductor for the MAX606 and a $10 \mu \mathrm{H}$ inductor for the MAX607. See Table 3 for a list of component suppliers. Higher inductor values allow greater load currents due to operation in continuous-conduction mode, while lower inductor values lead to smaller physical size due to lower energy-storage requirements and lower output-filter-capacitor requirements. Potential drawbacks of using lower inductor values are increased output ripple, lower efficiency, and lower out-put-current capability due to operation in discontinu-ous-conduction mode. (See the Maximum Output Current vs. Inductor Value graph in the Typical Operating Characteristics.)
The inductor must have a saturation (incremental) current rating equal to the peak switch-current limit, which is 1.1A. For highest efficiency, minimize the inductor's DC resistance.

# Low-Profile, 5V/12V or Adjustable, Step-Up DC-DC Converters for Flash Memory/PCMCIA Cards 

## Diode Selection

The MAX606/MAX607's high switching frequency demands a high-speed rectifier. Use a Schottky diode with at least a 0.5 A average current rating and a 1.2 A peak current rating, such as an MBR0520L. See Table 3 for a list of component suppliers.

## Capacitor Selection

Output Filter Capacitor
The output voltage ripple is a function of the output capacitor's equivalent series resistance (ESR) and capacitance. For best performance, use ceramic capacitors. Higher-ESR capacitors, such as tantalums, will cause excessive ripple. See Table 3 for a list of component suppliers.
The output voltage ripple is approximately $100 \mathrm{mVp}-\mathrm{p}$ for the 12V Standard Application Circuit (Figure 1) and 50 mV for the 5 V circuit (Figure 2). To further reduce this ripple, or to reduce the ripple on a different application circuit, increase the value of the output filter capacitor. If this capacitor is low ESR (e.g., ceramic), the output voltage ripple will be dominated by this capacitance.

Input Bypass Capacitors For applications where the MAX606/MAX607 are physically close to the input supply's filter capacitor (e.g., in PCMCIA drivers from the host computer), the input bypass capacitor may not be necessary.

In other applications where the MAX606/MAX607 are more than a few inches a away from the supply (such as memory cards), the input bypass capacitor is needed to reduce reflected current ripple to the supply and improve efficiency by creating a low-impedance path for the ripple current. Under these circumstances, the associated high Q and low ESR of ceramic capacitors do not diminish the problem. Therefore, include some low-Q, moderate-ESR capacitance (e.g., tantalum) at the input in order to reduce ringing. See Table 3 for a list of component suppliers.

Layout
The MAX606/MAX607's high-frequency operation and high peak currents make PC board layout critical to minimize ground bounce and noise. Locate input bypass and output filter capacitors as close to the device pins as possible. All connections to OUT (and to FB when operating in adjustable-output mode) should also be kept as short as possible. A ground plane is recommended. Solder GND and PGND directly to the ground plane. Refer to the MAX606/MAX607 evaluation kit manual for a suggested surface-mount layout.

## Low-Profile, 5V/12V or Adjustable, Step-Up

 DC-DC Converters for Flash Memory/PCMCIA CardsMAX606/MAX607


TRANSISTOR COUNT: 613
SUBSTRATE CONNECTED TO GND.
Package Information


